

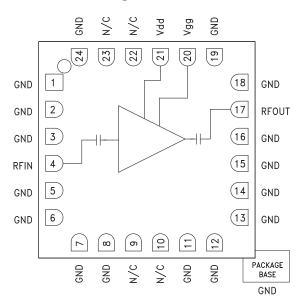


## **Typical Applications**

This HMC504LC4B is ideal for:

- Point-to-Point Radios
- Point-to-Multi-Point Radios
- Military & Space
- Test Instrumentation

## **Functional Diagram**



# HMC504LC4B

# GaAs HEMT MMIC LOW NOISE AMPLIFIER, 14 - 27 GHz

#### Features

Noise Figure: 2.2 dB @ 20 GHz Gain: 19 dB P1dB Output Power: +17 dBm Supply Voltage: +4V @ 90mA Output IP3: +26 dBm 50 Ohm matched Input/Output 24 Lead 4x4mm SMT Package: 16mm<sup>2</sup>

## **General Description**

The HMC504LC4B is a GaAs MMIC Low Noise Wideband Amplifier housed in a leadless 4x4 mm ceramic surface mount package. The amplifier operates between 14 and 27 GHz, providing up to 19 dB of small signal gain, 2.2 dB noise figure, and output IP3 of +26 dBm, while requiring only 90 mA from a +4V supply. The P1dB output power of up to +17 dBm enables the LNA to function as a LO driver for balanced, I/Q or image reject mixers. The HMC504LC4B also features I/Os that are DC blocked and internally matched to 50 Ohms, making it ideal for high capacity microwave radios or VSAT applications. This versatile LNA is also available in die form as the HMC-ALH476.

## Electrical Specifications, $T_A = +25 \text{ °C}$ , Vdd = +4V, Idd = 90 mA<sup>[2]</sup>

Parameter	Min.	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.	Units
Frequency Range		14 - 20	l		20 - 24			24 - 27		GHz
Gain <sup>[1]</sup>	16.5	19		16	18.5		14	17		dB
Gain Variation over Temperature		0.015			0.017			0.018		dB/°C
Noise Figure [1]		2.2	3		2.5	4.2		4.5	6	dB
Input Return Loss		15			9			7		dB
Output Return Loss		15			12			9.5		dB
Output Power for 1 dB Compression [1]		15			16.5			17		dBm
Saturated Output Power (Psat) [1]		19.5			19.5			19		dBm
Output Third Order Intercept (IP3)		24.5			25.5			26		dBm
Supply Current (Idd) (Vdd = 4V, Vgg = -0.3V Typ.)		90			90			90		mA

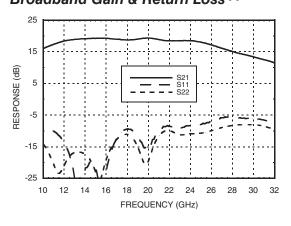
[1] Board loss subtracted out for gain, power and noise figure measurement [2] Adjust Vgg between -1 to 0.3V to achieve Idd = 90mA

For price, delivery and to place orders: Hittite Microwave Corporation, 20 Alpha Road, Chelmsford, MA 01824 Phone: 978-250-3343 Fax: 978-250-3373 Order On-line at www.hittite.com Application Support: Phone: 978-250-3343 or apps@hittite.com

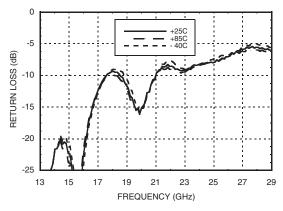




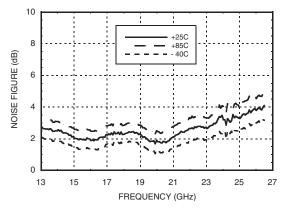
# Broadband Gain & Return Loss [1]



Input Return Loss vs. Temperature



Noise Figure vs. Temperature [1]

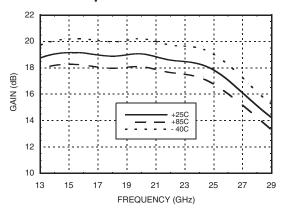


## [1] Board loss subtracted out for gain, power and noise figure measurement

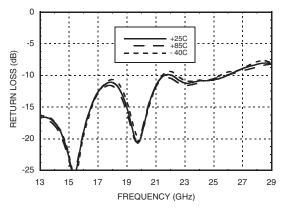
HMC504LC4B

## GaAs HEMT MMIC LOW NOISE AMPLIFIER, 14 - 27 GHz

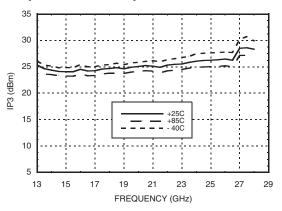
Gain vs. Temperature [1]



#### **Output Return Loss vs. Temperature**



**Output IP3 vs. Temperature** 



AMPLIFIERS - LOW NOISE - SMT

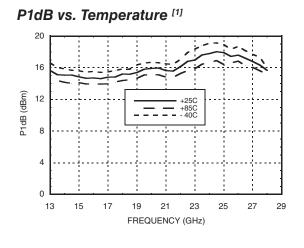
For price, delivery and to place orders: Hittite Microwave Corporation, 20 Alpha Road, Chelmsford, MA 01824 Phone: 978-250-3343 Fax: 978-250-3373 Order On-line at www.hittite.com Application Support: Phone: 978-250-3343 or apps@hittite.com



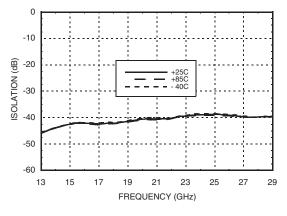


# HMC504LC4B

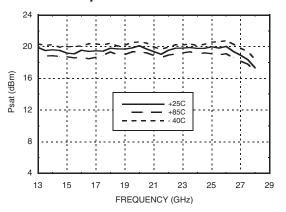
# GaAs HEMT MMIC LOW NOISE AMPLIFIER, 14 - 27 GHz



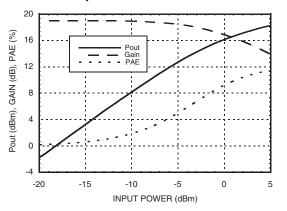
**Reverse Isolation vs. Temperature** 

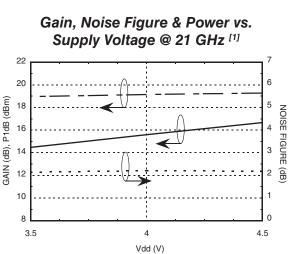


Psat vs. Temperature [1]



Power Compression @ 21 GHz [1]





 $\left[ 1\right]$  Board loss subtracted out for gain, power and noise figure measurement

For price, delivery and to place orders: Hittite Microwave Corporation, 20 Alpha Road, Chelmsford, MA 01824 Phone: 978-250-3343 Fax: 978-250-3373 Order On-line at www.hittite.com Application Support: Phone: 978-250-3343 or apps@hittite.com



# HMC504LC4B

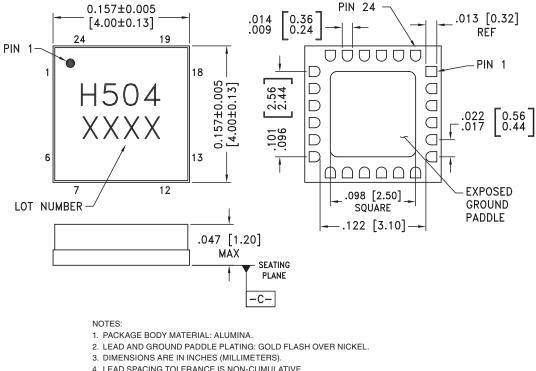
## GaAs HEMT MMIC LOW NOISE AMPLIFIER, 14 - 27 GHz

## Absolute Maximum Ratings

	]
Drain Bias Voltage	+4.5V
RF Input Power	+6 dBm
Gate Bias Voltage	-1 to 0.3V
Channel Temperature	180 °C
Continuous Pdiss (T = 85 °C) (derate 20 mW/°C above 85 °C)	1.9 W
Thermal Resistance (Channel to die bottom)	50 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-55 to +85 °C



## **Outline Drawing**



4. LEAD SPACING TOLERANCE IS NON-CUMULATIVE.

- 5. PACKAGE WARP SHALL NOT EXCEED 0.05MM DATUM -C-
- 6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.

BOTTOM VIEW





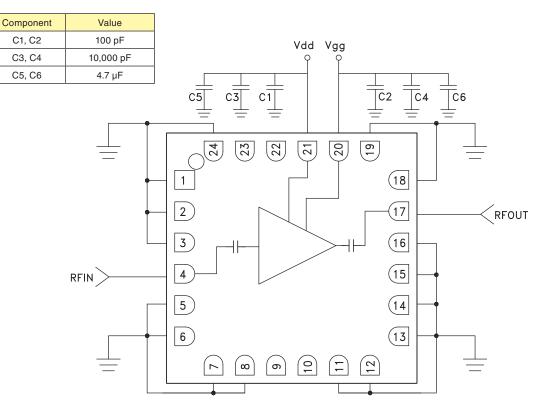
## GaAs HEMT MMIC LOW NOISE AMPLIFIER, 14 - 27 GHz

# ROHS V EARTH FRIENDLY

## **Pin Descriptions**

Pin Number	Function	Description	Interface Schematic	
1 - 3, 5 - 8, 11 - 16, 18, 19, 24	GND	Package bottom has exposed metal paddle that must be connected to RF/DC ground.		
4	RFIN	This pad is AC coupled and matched to 50 Ohms.		
17	RFOUT	This pad is AC coupled and matched to 50 Ohms.		
20	Vgg	Gate control for amplifier. Please follow "MMIC Amplifier Bias- ing Procedure" application note. See assembly for required external components.	Vgg o	
21	Vdd	Power Supply Voltage for the amplifier. See assembly for required external components.	Vdd o	

# Application Circuit



For price, delivery and to place orders: Hittite Microwave Corporation, 20 Alpha Road, Chelmsford, MA 01824 Phone: 978-250-3343 Fax: 978-250-3373 Order On-line at www.hittite.com Application Support: Phone: 978-250-3343 or apps@hittite.com

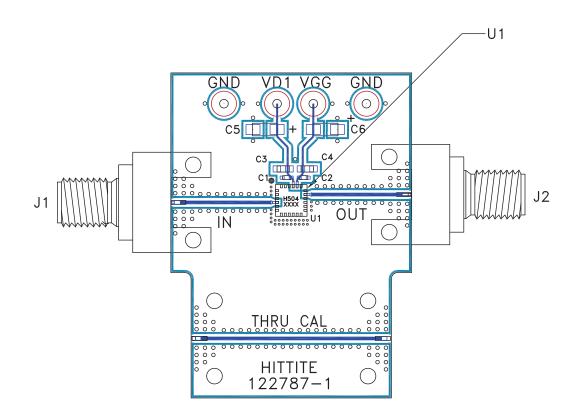


# HMC504LC4B

## GaAs HEMT MMIC LOW NOISE AMPLIFIER, 14 - 27 GHz



## **Evaluation PCB**



## List of Materials for Evaluation PCB 122789 [1]

Item	Item Description	
J1, J2	2.92mm PCB mount K-Connector	
J3 - J6	DC Pin	
C1, C2	100 pF Capacitor, 0402 Pkg.	
C3, C4	10,000pF Capacitor, 0603 Pkg.	
C5, C6	4.7 µF Capacitor, Tantalum	
U1	HMC504LC4B Amplifier	
PCB [2]	122787 Evaluation PCB <sup>[3]</sup>	

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350 or Arlon 25FR

[3] Due to the very high frequency operation of this product a custom LC4B PCB footprint and solder stencil are required for this design. Performance shown in this data sheet was produced using this custom footprint. DO NOT USE Hittite's standard LC4B footprint. Please contact Applications for details.

The circuit board used in this application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Hittite upon request.